# Vishay Semiconductors

High Voltage, Input Rectifier Diode, 80 A



PRIMARY CHARACTERISTICS								
I <sub>F(AV)</sub> 80 A								
V <sub>R</sub>	800 V to 1200 V							
V <sub>F</sub> at I <sub>F</sub>	1.17 V							
IFSM	1500 A							
T <sub>J</sub> max.	150 °C							
Package	TO-247AC 3L							
Circuit configuration	Single							

### **FEATURES**

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- Designed and qualified according to JEDEC<sup>®</sup>-JESD 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **APPLICATIONS**

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

### DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I <sub>F(AV)</sub>	Sinusoidal waveform	80	A					
V <sub>RRM</sub>	Range	800/1200	V					
I <sub>FSM</sub>		1500	A					
V <sub>F</sub>	80 A, T <sub>J</sub> = 25 °C	1.17	V					
TJ		-40 to +150	°C					

VOLTAGE RATINGS									
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA						
VS-80APS08-M3	800	900	1.5						
VS-80APS12-M3	1200	1300	1.5						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS					
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 100 \ ^{\circ}C$ , 180° conduction half sine wave	80						
Maximum peak one cycle non-repetitive surge current		10 ms sine pulse, rated $V_{\text{RRM}}$ applied	1450	A					
	IFSM	10 ms sine pulse, no voltage reapplied	1500						
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated $V_{\text{RRM}}$ applied	10 500	A <sup>2</sup> s					
Maximum 14 for fusing	141	10 ms sine pulse, no voltage reapplied	sine pulse, no voltage reapplied 14 000						
Maximum I <sup>2</sup> $\sqrt{t}$ for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	140 000	A²√s					



RoHS COMPLIANT

FREE



# VS-80APS..-M3 Series



**Vishay Semiconductors** 

ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
Maximum forward voltage drop	V <sub>FM</sub>	80 A, T <sub>J</sub> = 25 °C		1.17	V				
Forward slope resistance	r <sub>t</sub>	T.I = 150 °C		3.17	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1j = 150 C		0.73	V				
Maximum rayaraa laakaga aurrant		T <sub>J</sub> = 25 °C	$V_{B} = Rated V_{BBM}$	0.1	mA				
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	V <sub>R</sub> = naleu V <sub>RRM</sub>	1.5	ШA				

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		T <sub>J</sub> , T <sub>Stg</sub>		-40 to 150	°C				
Maximum thermal resistance, junction to case		R <sub>thJC</sub>	DC operation	0.35					
Maximum thermal resistance, junction to ambient		R <sub>thJA</sub>		40	°C/W				
Typical thermal resistance, case to heatsink		R <sub>thCS</sub>	Mounting surface, flat, smooth and greased	0.2					
Approvimente uneight				6	g				
Approximate weight				0.21	oz.				
Mounting torgue	minimum			6 (5)	kgf ⋅ cm				
Mounting torque	maximum			12 (10)	(lbf ⋅ in)				
Marking device				80APS08					
			Case style TO-247AC 3L	80APS12					

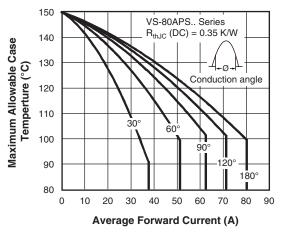


Fig. 1 - Current Rating Characteristics

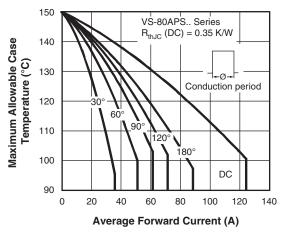


Fig. 2 - Current Rating Characteristics



## **Vishay Semiconductors**

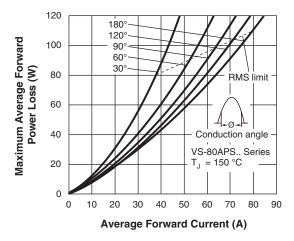


Fig. 3 - Forward Power Loss Characteristics

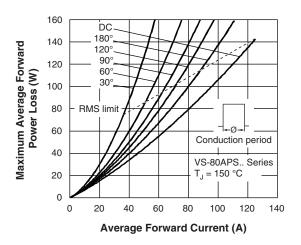
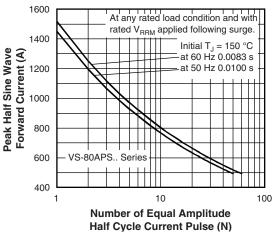


Fig. 4 - Forward Power Loss Characteristics





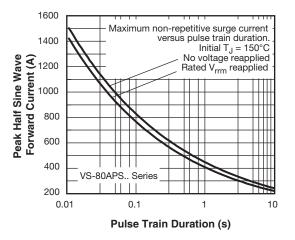


Fig. 6 - Maximum Non-Repetitive Surge Current

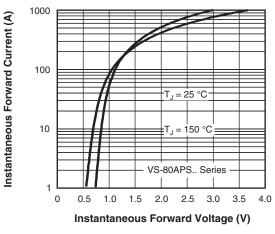


Fig. 7 - Forward Voltage Drop Characteristics

# VS-80APS..-M3 Series

**Vishay Semiconductors** 

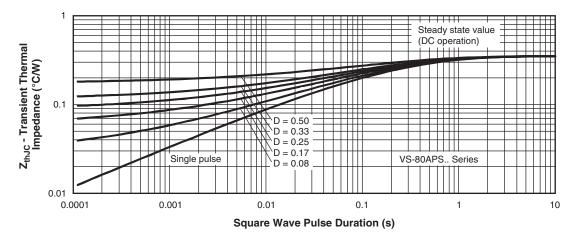


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

## **ORDERING INFORMATION TABLE**

www.vishay.com

Device code	VS-	80	Α	Р	S	12	-M3
		2	3	4	5	6	
	1 -	· Vish	nay Sem	iconduc	tors pro	duct	
	2 -			ng (80 =	,		
	3 -			guration liode, 3			
	4	- Pac	kage:				
		-	TO-247 e of silic				
	5			d recove	ery recti	fier _	
	6 -		age ratii	-			08 = 80 12 = 12
	7			ital digit: jen-free,		_ complia	nt and
		-1013	- naiog	en-nee,	10113-	complia	ni, anu

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-80APS08-M3	25	500	Antistatic plastic tubes					
VS-80APS12-M3	25	500	Antistatic plastic tubes					

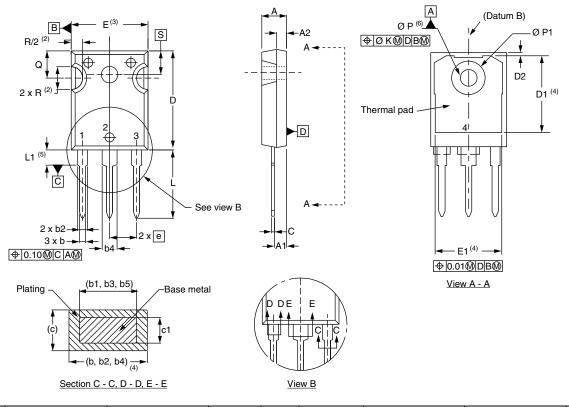
LINKS TO RELATED DOCUMENTS							
Dimensions www.vishay.com/doc?96138							
Part marking information	www.vishay.com/doc?95007						
SPICE model	www.vishay.com/doc?95550						



**Vishay Semiconductors** 

TO-247AC 3L

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
A	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	5 BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0	)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØΡ	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	' BSC	
D1	13.08	-	0.515	-	4							

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Thermal pad contour optional with dimensions D1 and E1

<sup>(5)</sup> Lead finish uncontrolled in L1

<sup>(6)</sup> Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

<sup>(7)</sup> Outline conforms to JEDEC<sup>®</sup> outline TO-247 with exception of dimension Q

Revision: 20-Jun-17

1

For technical questions within your region: DiodesAmericas@vishay.com, DiodesAsia@vishay.com, DiodesEurope@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com



Vishay

# Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.

单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)